SN74AHC125QPWR

Quality, reliability & packaging data download

Status: ACTIVE

Report date: 08/23/2022



Assembly site: TI MALAYSIA A/T

RoHS Yes

REACH Yes

Device marking HA125Q

Lead finish/Ball material NIPDAU

MSL rating/Peak reflow Level-1-260C-UNLIM

Rating Automotive



Material content

				Homogeneous N	laterial Level	Component Level	
Component	Substance	CAS Number	Amount (mg)	Percentage %	ppm	Percentage %	ppm
Bond Wire							
Other Nonferrous Metals and Alloys	Yttrium	7440-65-5	0.000001	0.000739	7	0.000002	0
Precious Metals	Gold	7440-57-5	0.135319	99.998522	999985	0.236603	2366
Precious Metals	Silver	7440-22-4	0.000001	0.000739	7	0.000002	0
Sub-total	_	_	0.135321	100	1000000	0.236606	2366
Die Attach Adhesive							
Precious Metals	Silver	7440-22-4	0.189853	80.000084	800001	0.331954	3320
Thermoplastics	Ероху	85954-11-6	0.047463	19.999916	199999	0.082988	830
Sub-total	_	_	0.237316	100	1000000	0.414942	4149
Lead Frame							
Copper and Its Alloys	Copper	7440-50-8	21.33279	21.33279 97.410000		37.299973	373000
Copper and Its Alloys	copper and its Alloys Iron		0.5256	2.400000	24000	0.919001	9190
Copper and Its Alloys	pys Phosphorus 7723-		0.00657	0.030000	300	0.011488	115
Other Nonferrous Metals and Alloys	Lead	7439-92-1	0.00657	0.030000	300	0.011488	115
Other Nonferrous Metals and Alloys	Tin	7440-31-5	0.00657	0.030000	300	0.011488	115
Zinc and Its Alloys	Zinc	7440-66-6	0.0219	0.100000	1000	0.038292	383
Sub-total	_	_	21.90000	100	1000000	38.291729	382917
Lead Frame Plating							
Nickel and Its Alloys	Nickel	7440-02-0	0.370968	95.120000	951200	0.648630	6486
Precious Metals	Gold	7440-57-5	0.003042	0.780000	7800	0.005319	53
Precious Metals	Palladium	7440-05-3	0.01599	4.100000	41000	0.027958	280
Sub-total	_	-	0.390000	100	1000000	0.681907	6819
Mold Compound							
Other Inorganic Materials	Fused Silica	60676-86-0	29.028477	86.000000	860000	50.755734	507557
Other Plastics and Rubber	Carbon Black	1333-86-4	0.101262	0.300000	3000	0.177055	1771
Thermoplastics	Ероху	85954-11-6	4.624304	13.700000	137000	8.085507	80855
Sub-total	_	_	33.754043	100	1000000	59.018295	590183
Semiconductor Device							
Ceramics / Glass	Doped Silicon	7440-21-3	0.775828	100.000000	1000000	1.356520	13565
Sub-total	-	_	0.775828	100	1000000	1.356520	13565
Total	_	_	57.192508	_	_	100	100000



MTBF/FIT estimates

MTBF / FIT MTBF / FIT supporting data									
MTBF	FIT	Usage temp (°C)	Conf level (%)	Activation energy (eV)	Test temp (°C)	Test duration (hours)	Sample size	Fails	Additional comments
9.3×10^8	1.1	55	60	0.7	125	1000	10859	0	_

Qualification summary

Туре	AEC Q100 test #	Test spec	Min lot qty	SS / lot	Test name	Condition	Result
Test group	A - accelerated	environment stress test					
THB/HAST	A2	JESD22-A101/JESD22-A110	3	77	Temperature humidity-bias or biased HAST	THB 85C/85%RH for 1000 hours or HAST 110C/85%RH for 264 hours or equivalent	Pass
AC/UHAST	A3	JESD22-A102/JESD22-A118	3	77	Autoclave or unbiased HAST	AC 121C for 96 hours or UHAST 110C/85%RH for 264 hours or equivalent	Pass
TC	A4	JESD22-A104	3	77	Temperature cycle	Per grade requirements. See data sheet.	Pass
TC-WBP	A4	MIL-STD883 method 2011	1	30	Post temp cycle bond pull	Per requirements	Pass
HTSL	A6	JESD22-A103	1	45	High temp storage bake	Per grade requirements. See data sheet.	Pass
Test group	B - accelerated	ifetime simulation test					
HTOL	B1	JESD22-A108	3	77	High temperature operating life	Per grade requirements. See data sheet.	Pass
ELFR	B2	AEC Q100-008	3	800	Early life failure rate	Per grade requirements. See data sheet.	Pass
Test group	C - package ass	embly integrity tests					
WBS	C1	AEC Q100-001	1	30	Wire bond shear	Cpk > 1.67	Pass
WBP	C2	MIL-STD883 method 2011	1	30	Wire bond pull	Cpk > 1.67	Pass
SD	C3	JEDEC J-STD-002D	1	15	Solderability	>95% lead coverage	Pass
PD	C4	JESD22-B100 and B108	3	10	Physical dimensions	Cpk > 1.67	Pass
Test group	D - die fabrication	on reliability tests					
EM	D1	_	_	_	Electromigration	Per technology requirements	Pass
TDDB	D2	_	_	_	Time dependent dielectric breakdown	Per technology requirements	Pass
HCI	D3	-	-	-	Hot carrier injection	Per technology requirements	Pass
NBTI	D4	_	_	-	Negative bias temperature instability	Per technology requirements	Pass
Test group	E - electrical ver	ification					
НВМ	E2	AEC Q100-002	1	3	Electrostatic discharge - human body model	Per AEC Q100-002	See data
CDM	E3	AEC Q100-011	1	3	Electrostatic discharge - charged device model	Per AEC Q100-011	See data
LU	E4	AEC Q100-004	1	6	Latch-up	Per AEC Q100-004	Pass
ED	E5	AEC Q100-009	3	30	Electrical distributions	Per AEC Q100-009	Pass



Ongoing reliability monitoring

FAB process reliability data

Fab Process	Reliability Test	Rolling Year (2Q21 - 1Q22) Sample Size	Cumulative Sample Size	Disposition
CMOS	High Temperature Operating Life, 125C, 1000 Hours (or Equivalent)	388	52086	Pass

Assembly process reliability data

Package Family	Reliability Test	Rolling Year (2Q21 - 1Q22) Sample Size	Cumulative Sample Size	Disposition
TSSOP	Autoclave, 121C, 96 Hours	1155	53383	Pass
TSSOP	Biased HAST, 110C/85%RH, 264 Hours	374	1220	Pass
TSSOP	Biased HAST, 130C/85%RH, 96 Hours	1267	34128	Pass
TSSOP	High Temperature Storage Life, 150C, 1000 Hours	1420	10513	Pass
TSSOP	High Temperature Storage Life, 170C, 420 Hours	154	16911	Pass
TSSOP	Temperature Cycle, -40/125C, 850 Cycles	0	82	Pass
TSSOP	Temperature Cycle, -55/125C, 700 Cycles	0	1403	Pass
TSSOP	Temperature Cycle, -65/150C, 500 Cycles	4255	75024	Pass
TSSOP	Temperature-Humidity Bias Test (85C/85%RH), 1000 Hours	0	1416	Pass
TSSOP	Unbiased HAST, 130C/85%RH, 96 Hours	716	8984	Pass



Additional resources

General quality guidelines

Certifications

Conflict minerals specialized disclosure report

Restricted chemical test report

For additional component information, please visit Material content search

For additional information, please contact TI customer support center

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